

ORNL is managed by UT-Battelle LLC for the US Department of Energy

SiPM expected

1.3x1.3 mm² SiPM (Outer region ~90%)

Very conservative estimates after radiation damage:

- 20 μA in small SiPM
- 100 μA in larger SiPM

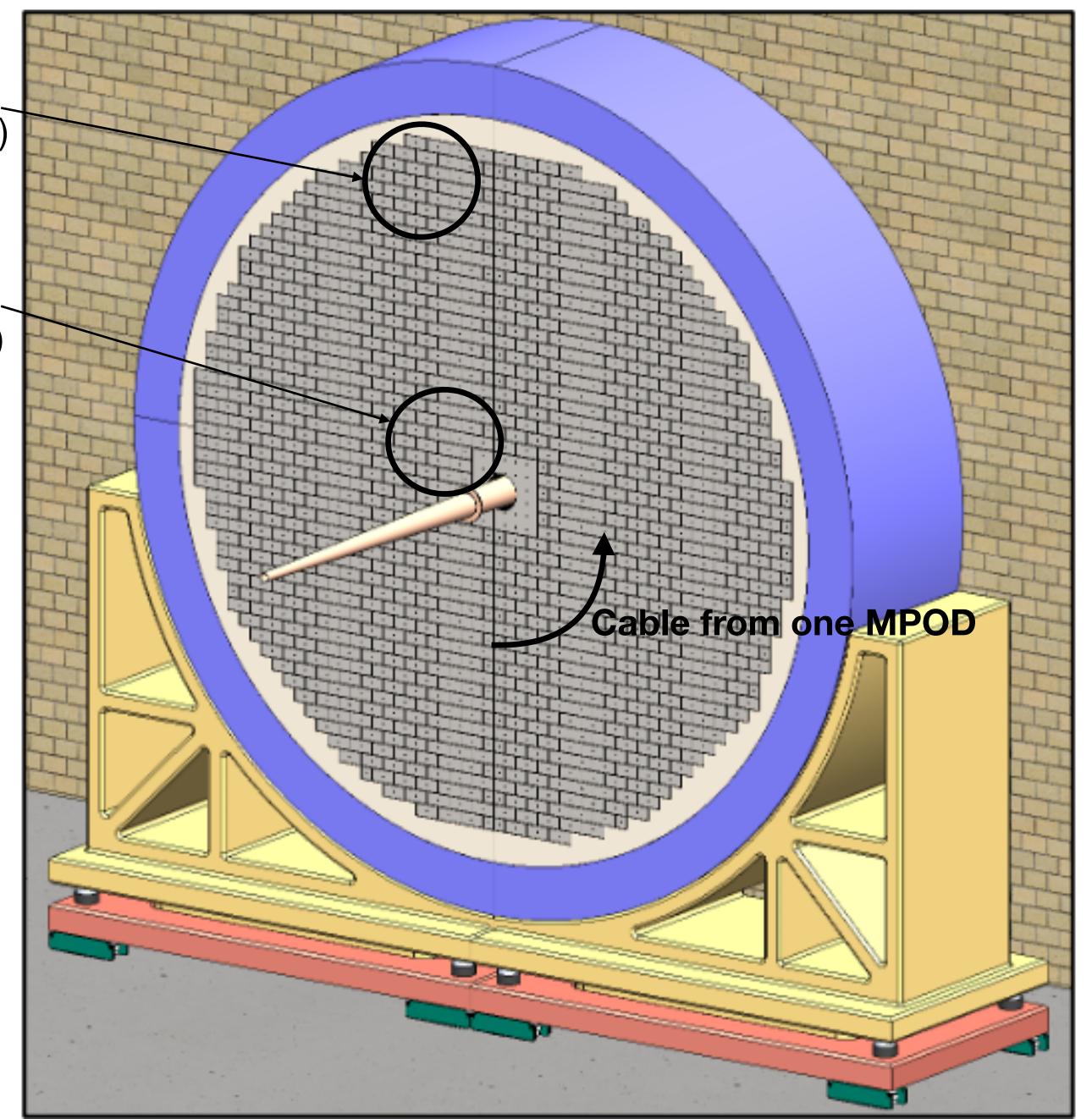
3x3 mm² SiPM (Inner region ~10%)

8M modules have in total 1 FEB, 520 SiPM:

- 10.4 mA per 8M module
- 52 mA per 8M module
- —> Total: ~16 Amp

Design consideration of connections:

- The two half have to slide away from each other (no cross connection)
- Concentric circular design:
 - Per channel of the MPOD:
 - Adjusting the same bias voltage to similar SiPM's
 - Receive similar amount of radiation
 - Need to study the exact radiation doses



FEB prototype

Current design (adopted to final FEB also):

- Single Bias voltage input to the FEB
- Enable/Disable HV input from the FPGA
- LED control light
- Monitor the bias voltage and/or the leakage current per FEB (part of the slow control

D2_A GREEN

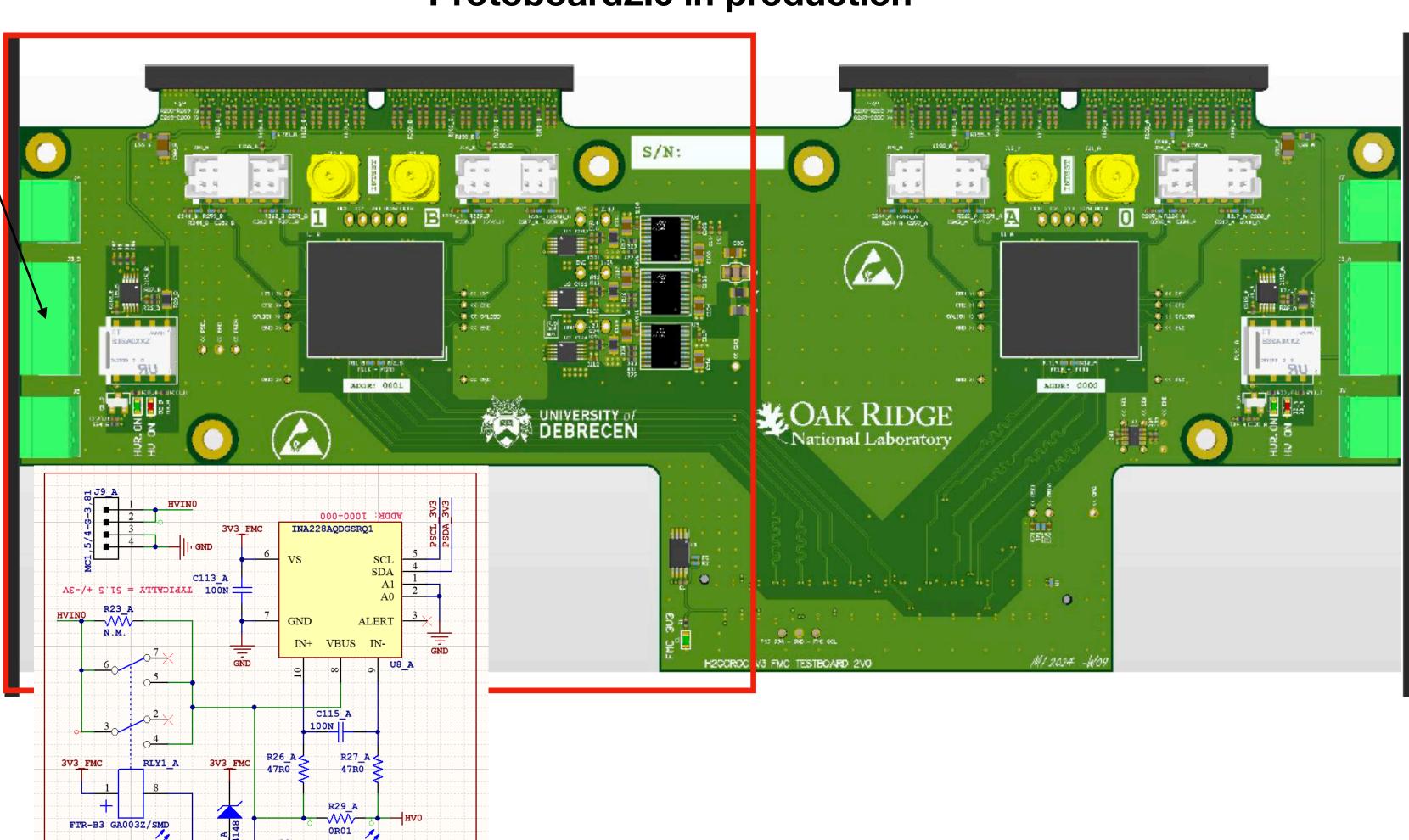
3V3_FMC

Q1_A BC817SMD

> C120_A 100P

> > Max. Res Value: 0.04R @ LA VSENSE MAX= +/-40.96mV

Protoboard2.0 in production



Initial FEB design

FEB design skeleton:

- It will evolve from the protoboard2.0 with some modification:
 - Remain the monitoring and bias handling
- All active electronics on the FEB
- Summing circuit:
 - We still do some R&D on this which one is the best, there are several ideas so far
- Will receive one common bias for all SiPM
 - HGCROC offers and adjustment inside the ASIC — need to figure out if it can be applied with a summing circuit

